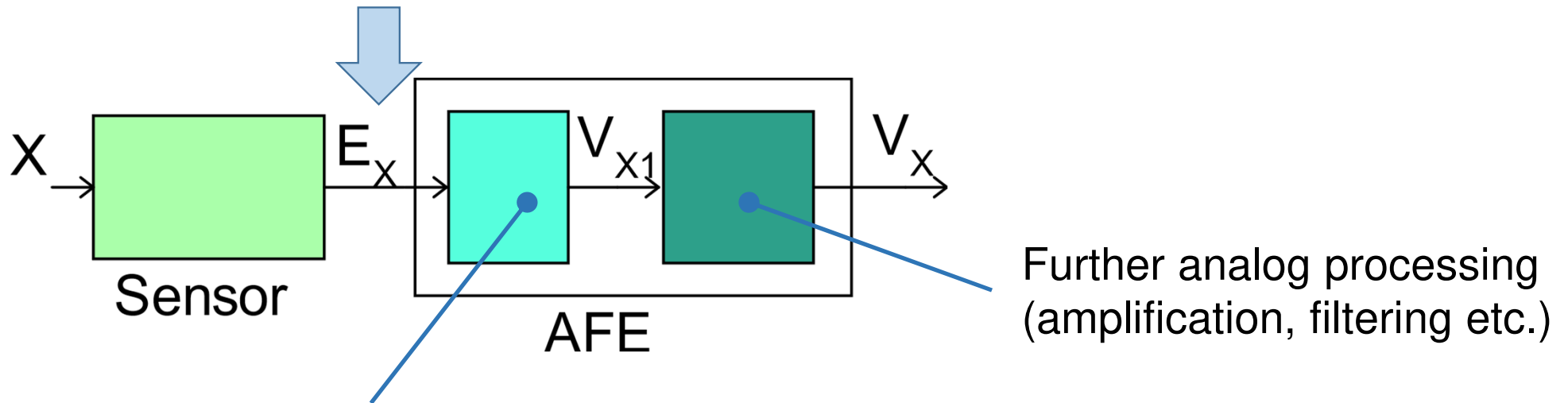


Sensor Interfaces



Sensor Interface: directly connected to the sensor. Detects the typically small variations of the electrical quantity E_x and convert it into a voltage, if required.

Sensors that produce a voltage

Output quantity	electrical	Sensor type	Input physical or chemical quantity to be sensed.
Voltage		Thermoelectric sensors	Temperature difference Temperature Fluid flow rate Infrared radiation (bolometers) Gas concentration (catalytic sensors)
		Electrochemical sensors	Ion concentration in electrolytes Gas concentration (e.g.. “lambda probes”)
		Hall sensors	Magnetic Field Position (Proximity) Current measurement
		Piezoelectric sensors	Force (ac detection) Acoustical pressure, acceleration.

Sensors that produce a current or a charge

Output electrical quantity	Sensor type	Input physical or chemical quantity to be sensed.
Current	Optical sensors (photodiodes)	Infrared, visible and Ultraviolet radiation
		Imagers Proximity Opacity (e.g. smoke detectors)
Charge	CCD imagers	Visible radiation
	High energy particle detectors	Ionizing radiation and particle detection

Resistive sensors

Output electrical quantity	Sensor type	Input physical or chemical quantity to be sensed
Resistance	Thermistor and RTDs (Resistive Temperature Detectors)	Temperature Fluid flow rates Fluid velocity (e.g. hot wire anemometers) Gas concentration (catalytic sensors) Proximity
	Piezo-resistors	Strain (strain gauges) Force (e.g. electronic scales) Pressure (barometers) Altitude Acceleration
	Chemi-resistors	Gas or vapor concentration
	Magneto-resistors	Magnetic field Proximity Orientation (e.g. electronic compass)
	Photo resistors	Visible radiation

Capacitive sensors

Output electrical quantity	Sensor type	Input physical or chemical quantity to be sensed.
Capacitance	Capacitive sensors (mechanical)	Acceleration Angular velocity (gyroscopes) Pressure
	Capacitive sensors (chemical)	Gas concentration (e.g. humidity sensors)

Frequently used sensor interfaces

Output quantity	Type of Interface	Notes
Voltage	Instrumentation Amplifier (In-Amp)	
Resistance	Instrumentation Amplifier	Resistors should be mounted in a Wheatstone bridge configuration or biased by a current.
	Trans-Impedance Amplifier (TIA)	Resistor must be biased with a voltage in order to produce a current
Current	Trans-Impedance Amplifier (TIA)	
Capacitance	Trans-Impedance Amplifier (TIA)	Converting capacitance into a current by means of a periodic voltage waveform
	Charge amplifier (switched capacitor)	
Charge	Charge amplifier (switched capacitors)	

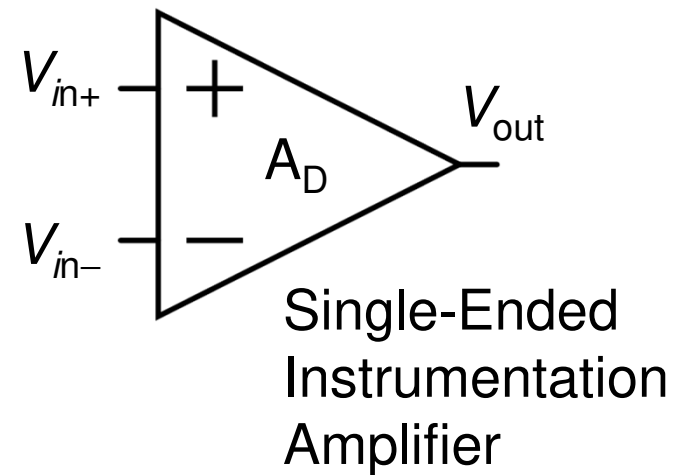
Instrumentation Amplifiers (In-Amps)

Required features:

- **Precise gain (A_D)**
- **High input resistance**

Other important features

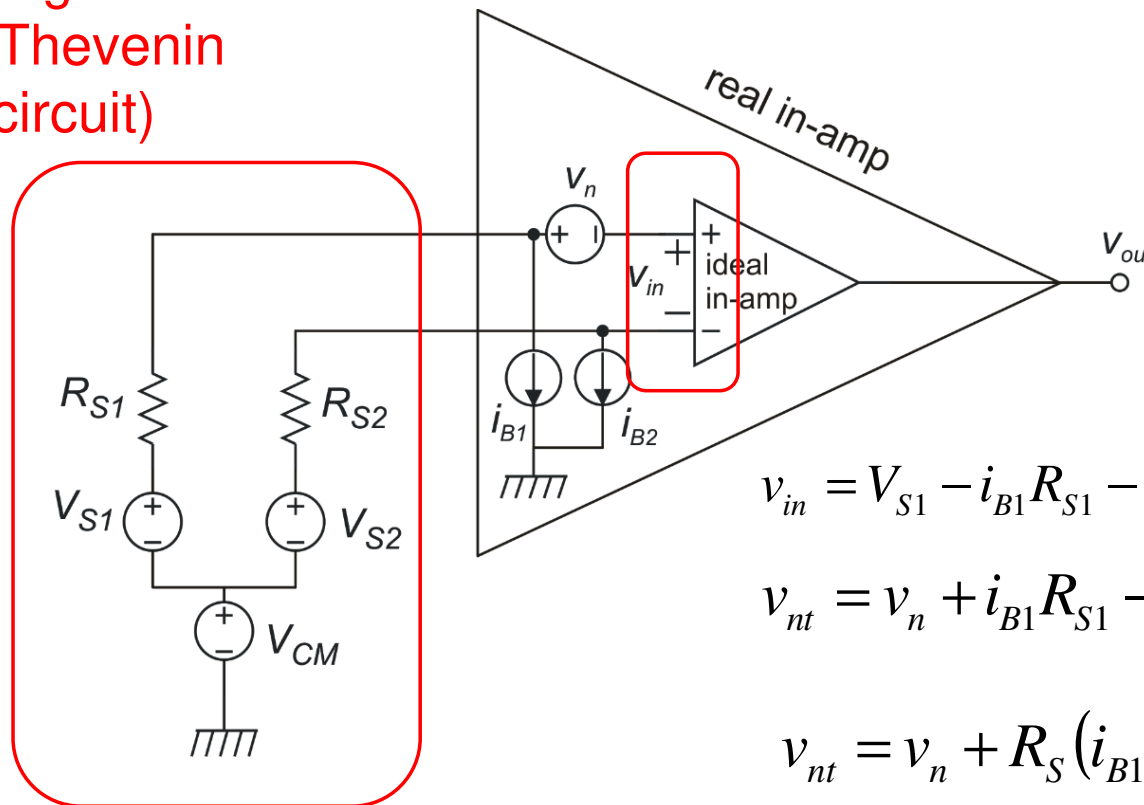
- **Differential input**
- Low input referred offset voltage
- Low bias currents
- Low input referred voltage and current noise
- High CMRR (for differential amplifiers)
- Large bandwidth



In-amps: errors due to the input noise/offset voltage and currents

Differential signal source
(Simplified Thevenin
equivalent circuit)

Useful Signal: $V_{S1} - V_{S2}$



$$v_{in} = V_{S1} - i_{B1}R_{S1} - v_n - (V_{S2} - i_{B2}R_{S2}) = V_{S1} - V_{S2} - v_{nt}$$

$$v_{nt} = v_n + i_{B1}R_{S1} - i_{B2}R_{S2}$$

$$v_{nt} = v_n + R_S(i_{B1} - i_{B2}) \quad \text{Balanced source case } (R_{S1}=R_{S2}=R_S)$$

Total voltage noise expressions

Balanced source
case ($R_{S1}=R_{S2}=R_S$)

$$v_{nt} = v_n + R_S (i_{B1} - i_{B2})$$

DC components:

$$v_n = v_{io} \quad i_{b1} = I_{B1}; \quad i_{b2} = I_{B2}; \quad (i_{B1} - i_{B2}) = I_{B1} - I_{B2} = I_{io}$$

$$v_{iot} = v_{io} + R_S I_{io}$$

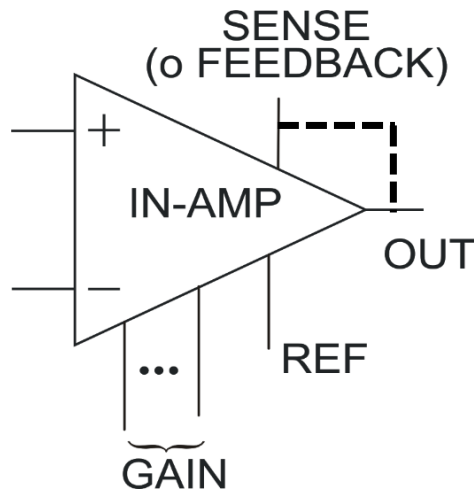
Noise components: $v_n \Rightarrow S_{vn}; \quad \begin{cases} i_{b1} = i_{n1} \Rightarrow S_{I1}(f) \\ i_{b2} = i_{n2} \Rightarrow S_{I2}(f) \end{cases} \quad S_{I12}(f)$

If i_{n1} and i_{n2} are uncorrelated and $S_{I1} = S_{I2} = S_I$:

$$S_{vnt} = S_{vn} + R_S^2 (S_{I1} + S_{I2} - 2S_{I1I2})$$

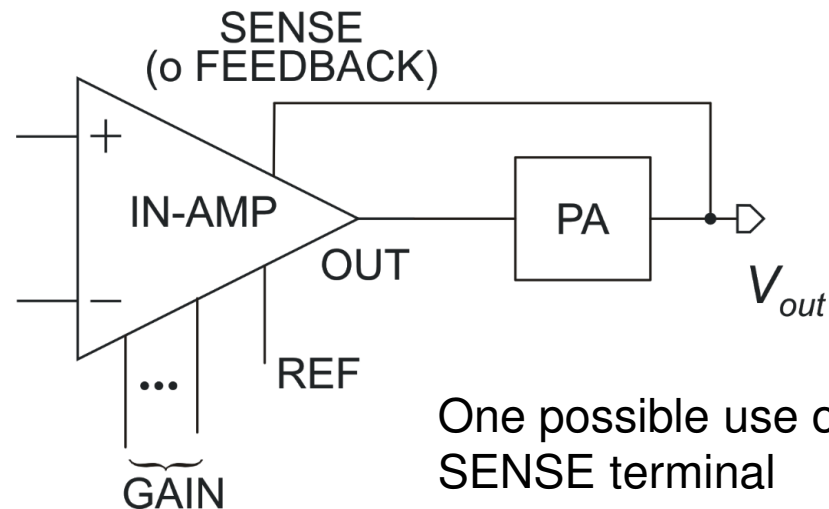
$$S_{vnt} = S_{vn} + 2R_S^2 S_I$$

Discrete monolithic In-Amps



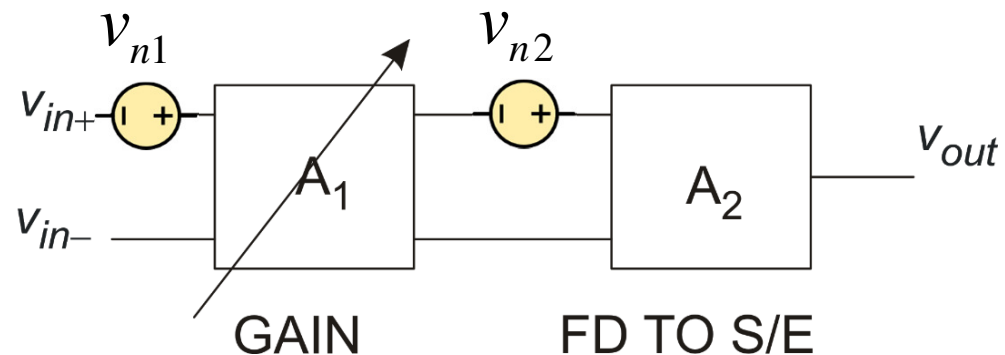
Typical pin configuration

$$V_{out} = G(V_{IN+} - V_{IN-}) + V_{REF}$$



One possible use of the SENSE terminal

In-Amp with variable gain: Input and Output offset and noise



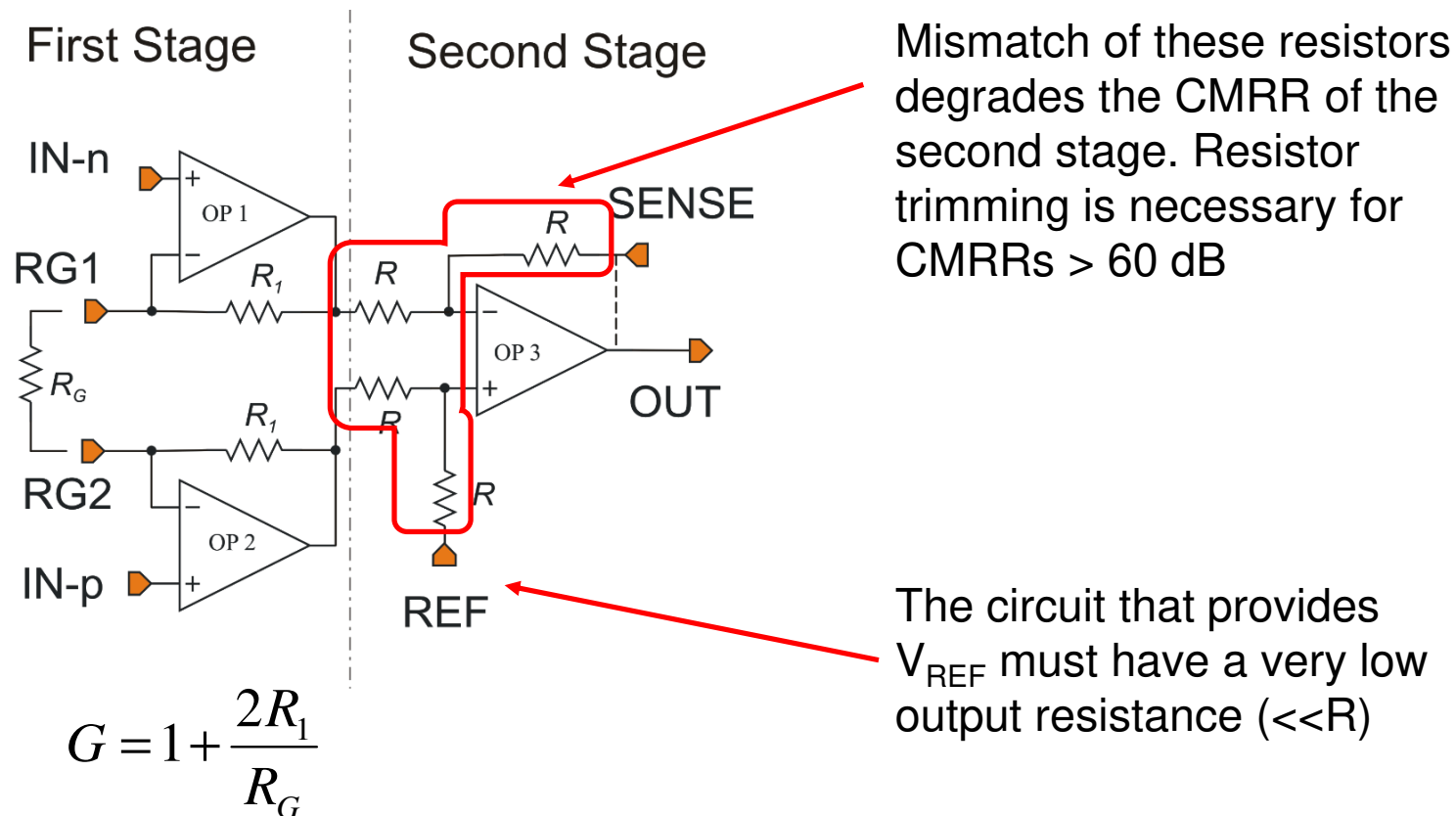
Typical two-stage architecture of In-amps $G = A_1 A_2$

$$v_{n-out} = v_{n1} A_1 A_2 + v_{n2} A_2 \quad v_{nRTI} = \frac{v_{n-out}}{G} = v_{n1} + \frac{v_{n2}}{A_1}$$

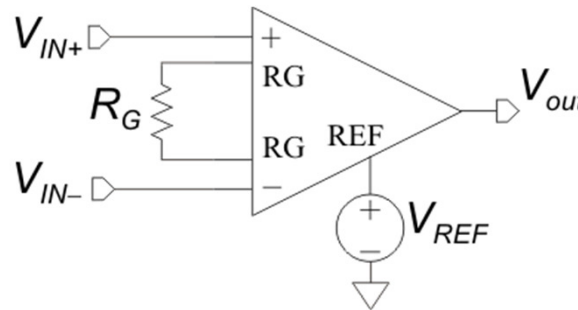
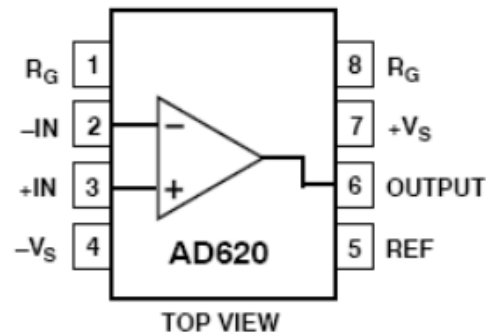
Generally, $A_2 = 1$, thus: $A_1 = G$ $v_{nRTI} = v_{n1} + \frac{v_{n2}}{G}$

v_{n1} : input noise
 v_{n2} : output noise

Three-Op-Amp Instrumentation Amplifier



AD 620



$$V_{out} = G(V_{IN+} - V_{IN-}) + V_{REF}$$

$$G = 1 + 49.4k\Omega / R_G$$

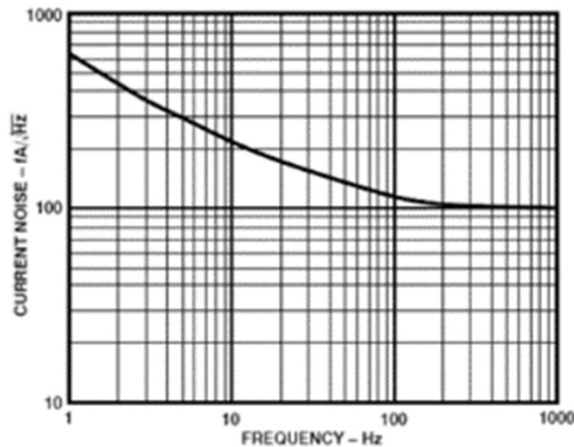


Figure 9. Current Noise Spectral Density vs. Frequency

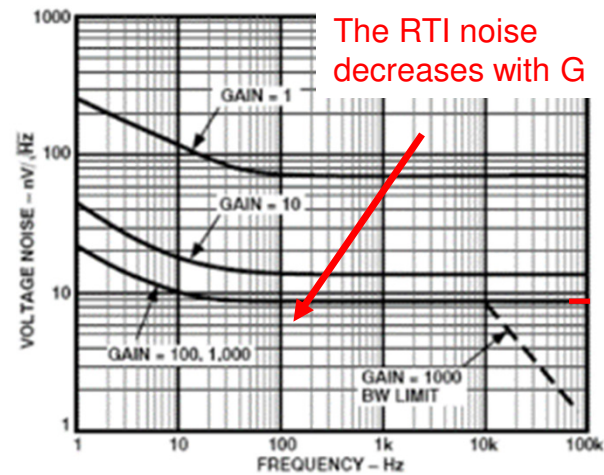


Figure 8. Voltage Noise Spectral Density vs. Frequency, (G = 1-1000)

The RTI noise decreases with G

At $G \geq 100$ the amplifier BW is larger than 100kHz. The noise density starts to fall for $f > 100\text{kHz}$

AD 620

GBW does not increase much beyond the G=10 case: BW affected by second stage
 Nearly constant GBW product: BW determined by first stage

AD620

Model	Conditions	Min	AD620A Typ	Max	Min	AD620B Typ	Max	Min	AD620S ¹ Typ	Max	Units
DYNAMIC RESPONSE											
Small Signal -3 dB Bandwidth											kHz
G = 1			1000			1000			1000		kHz
G = 10			800			800			800		kHz
G = 100			120			120			120		kHz
G = 1000			12			12			12		kHz
Slew Rate		0.75	1.2		0.75	1.2		0.75	1.2		V/μs
Settling Time to 0.01%	10 V Step										μs
G = 1-100			15			15			15		μs
G = 1000			150			150			150		μs
NOISE											
Voltage Noise, 1 kHz	$Total\ RTI\ Noise = \sqrt{(e_{ni}^2) + (e_{no}/G)^2}$										nV/√Hz
Input, Voltage Noise, e_{ni}			9	13		9	13		9	13	nV/√Hz
Output, Voltage Noise, e_{no}			72	100		72	100		72	100	nV/√Hz
RTI, 0.1 Hz to 10 Hz											μV p-p
G = 1			3.0			3.0	6.0		3.0	6.0	μV p-p
G = 10						0.55	0.8		0.55	0.8	μV p-p
G = 100-1000						0.28	0.4		0.28	0.4	μV p-p
Current Noise	f = 1 kHz		100			100			100		fA/√Hz
0.1 Hz to 10 Hz			10			10			10		pA p-p

Settling times

Slew -Rate

Output noise >> input noise

Broad-Band Noise: $\sqrt{S_{BB}}$

Broad-Band Noise: $\sqrt{S_{BB}}$

Current

Low Frequency Noise
Integrated over 0.1-10 Hz

Low Frequency Noise
Integrated over 0.1-10 Hz

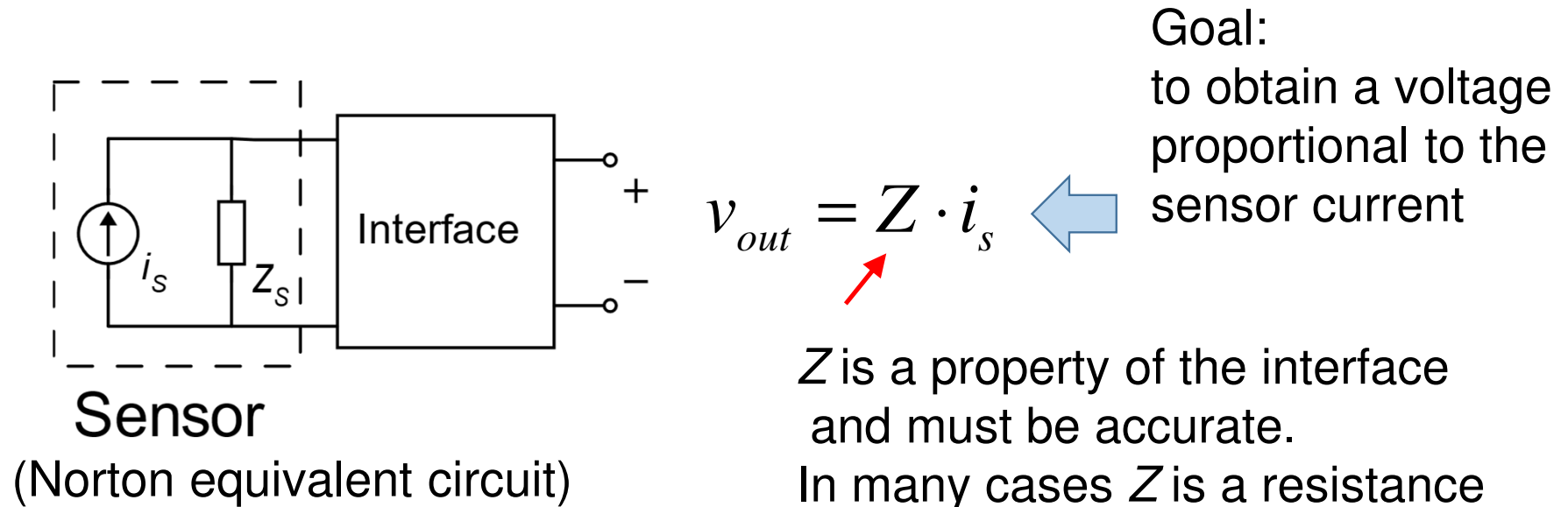
The effective input referred offset (RTI) is a combination of the input and output offset

AD 620

VOLTAGE OFFSET		(Total RTI Error = $V_{OSI} + V_{OSO}/G$)		Input offset		Output offset	
Input Offset, V_{OSI}	$V_S = \pm 5 \text{ V to } \pm 15 \text{ V}$	30	125	15	50	30	125
Over Temperature	$V_S = \pm 5 \text{ V to } \pm 15 \text{ V}$		185		85		225
Average TC	$V_S = \pm 5 \text{ V to } \pm 15 \text{ V}$	0.3	1.0	0.1	0.6	0.3	1.0
Output Offset, V_{OSO}	$V_S = \pm 15 \text{ V}$	400	1000	200	500	400	1000
	$V_S = \pm 5 \text{ V}$		1500		750		1500
Over Temperature	$V_S = \pm 5 \text{ V to } \pm 15 \text{ V}$		2000		1000		2000
Average TC	$V_S = \pm 5 \text{ V to } \pm 15 \text{ V}$	5.0	15	2.5	7.0	5.0	15
Offset Referred to the Input vs. Supply (PSR)	$V_S = \pm 2.3 \text{ V to } \pm 18 \text{ V}$						
G = 1		80	100	80	100	80	100
G = 10		95	120	100	120	95	120
G = 100		110	140	120	140	110	140
G = 1000		110	140	120	140	110	140
INPUT CURRENT							
Input Bias Current		0.5	2.0	0.5	1.0	0.5	2
Over Temperature			2.5		1.5		4
Average TC		3.0		3.0		8.0	
Input Offset Current		0.3	1.0	0.3	0.5	0.3	1.0
Over Temperature			1.5		0.75		2.0
Average TC		1.5		1.5		8.0	
POWER SUPPLY							
Operating Range ⁴	$V_S = \pm 2.3 \text{ V to } \pm 18 \text{ V}$	± 2.3	± 18	± 2.3	± 18	± 2.3	± 18
Quiescent Current		0.9	1.3	0.9	1.3	0.9	1.3
Over Temperature		1.1	1.6	1.1	1.6	1.1	1.6

The AD 620 in-amp represents a good trade-off between input noise voltage, input bias currents and supply current (quiescent current)

Interfacing a sensor whose output is a current

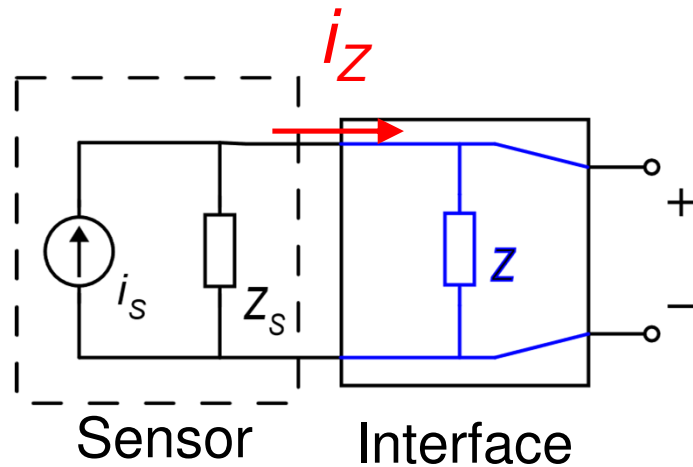


i_s is the quantity to be read, since it contains the useful information

Z_s is the unavoidable output impedance of the sensor.

The ideal case is an infinite Z_s (ideal current source)

The simplest solution



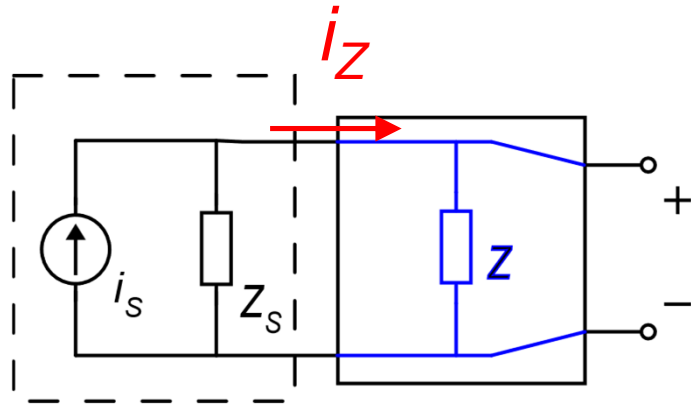
Simply connect a known impedance across the sensor terminals

$$V_{out} = Z \cdot i_Z$$

$$i_Z = \frac{Z_s}{Z_s + Z} i_s = \frac{1}{1 + \frac{Z}{Z_s}} i_s$$

$$i_Z \neq i_s$$

Sensitivity vs Accuracy



$$v_{out} = Z \cdot i_z$$

$$i_z = \frac{1}{1 + \frac{Z}{Z_s}} i_s \cong \left(1 - \frac{Z}{Z_s} \right) i_s$$

$$v_{out} \cong Z \left(1 - \frac{Z}{Z_s} \right) i_s$$

$$v_{out} = Z \cdot i_s$$

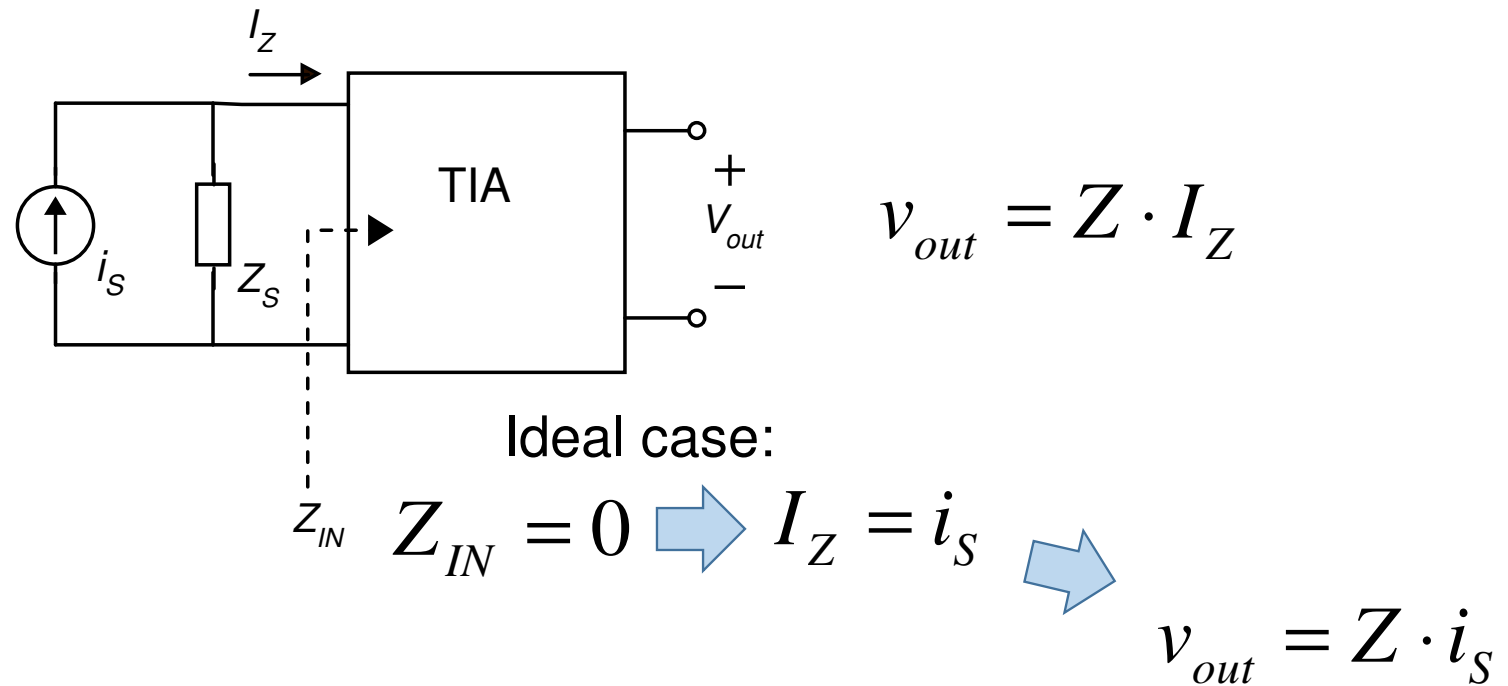
Nominal law

Z should be large (magnitude) to obtain a high sensitivity

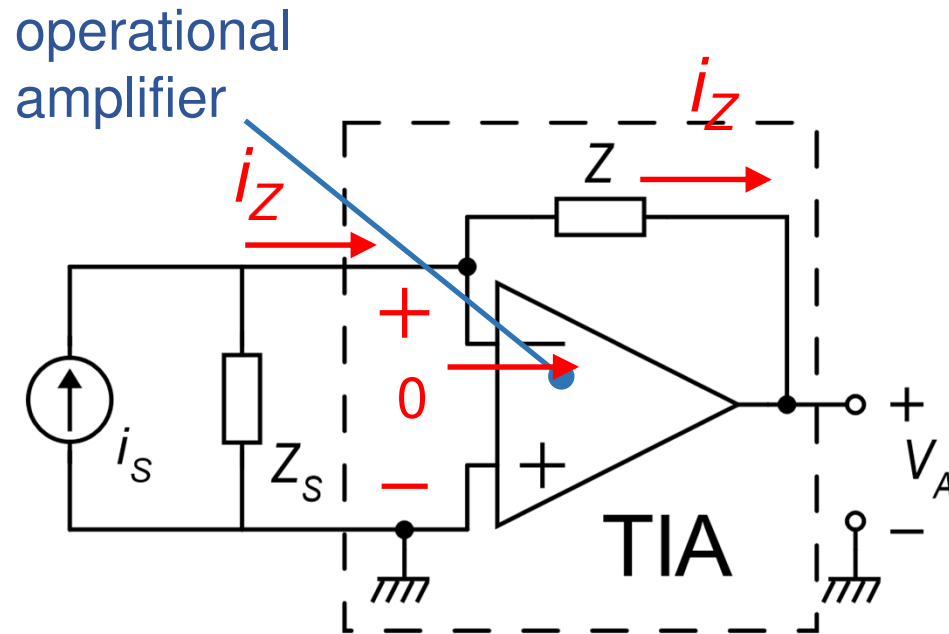
Z should be small (magnitude) to reduce the relative error (high accuracy)

For sensor marked by small values of the Z_s impedance, finding a value of Z that satisfies both requirements is often impossible

A better interface: the Trans-Impedance Amplifier (TIA)



The op-amp based TIA



Ideal case (perfect virtual gnd)

$$V_{IN} = 0 \Rightarrow Z_{IN} = 0$$

$$I_Z = i_S$$

$$v_A = -Z \cdot I_Z = -Z \cdot i_S$$

Sensitivity of the TIA stage
(transimpedance)

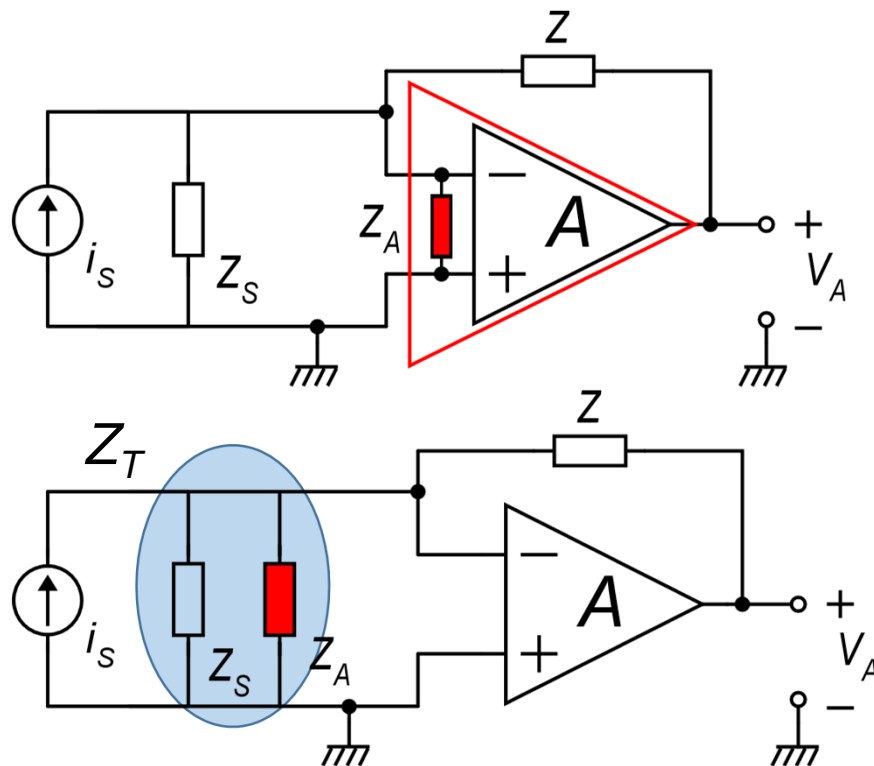
$$k_{TIA} = \frac{v_{An}}{i_s} = -Z$$

TIA non-idealities

- Finite gain
- Finite input impedance

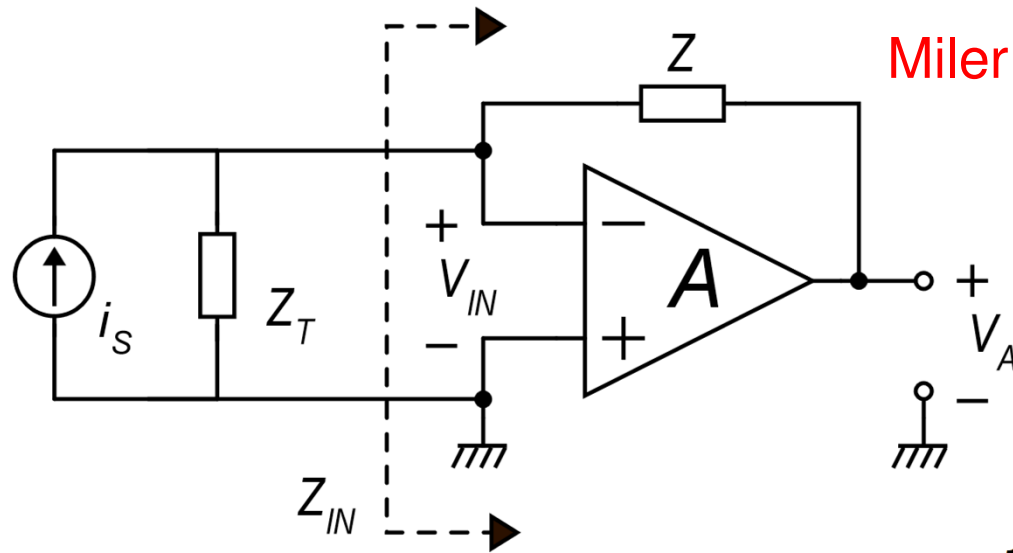
$$A = \frac{A_0}{1 + j \frac{f}{f_p}}$$

Typical dominant-pole frequency response



$$Z_T = Z_S // Z_A$$

$Z_T = Z_S // Z_A$ TIA: input impedance Z_{IN}



Miler Effect:

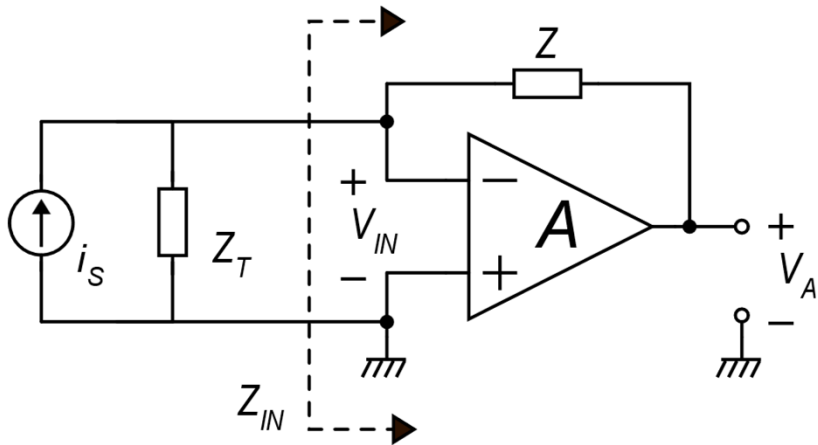
$$Z_{IN} = \frac{Z}{1 - K_M} \quad K_M = \frac{v_{out}}{v_{in}} = -A$$

$$Z_{IN} = \frac{Z}{1 + A}$$

$$Z_{IN} = Z \frac{1}{1 + \frac{A_0}{1 + j \frac{f}{f_p}}} = Z \frac{1 + j \frac{f}{f_p}}{1 + A_0 + j \frac{f}{f_p}} = \frac{Z}{1 + A_0} \left[\frac{1 + j \frac{f}{f_p}}{1 + j \frac{f}{(1 + A_0) f_p}} \right]$$

$\cong f_0$

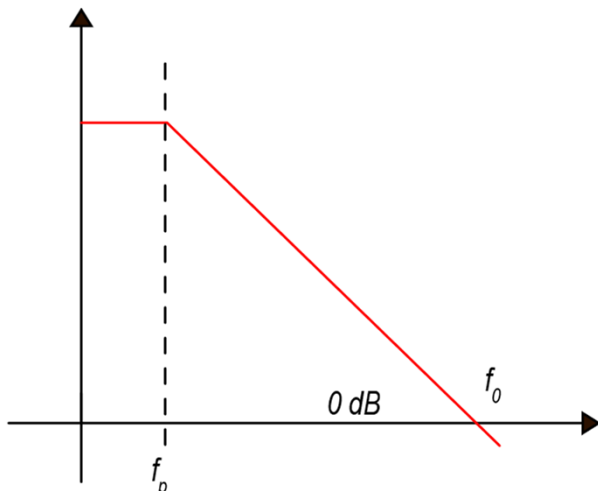
TIA: input impedance Z_{IN}



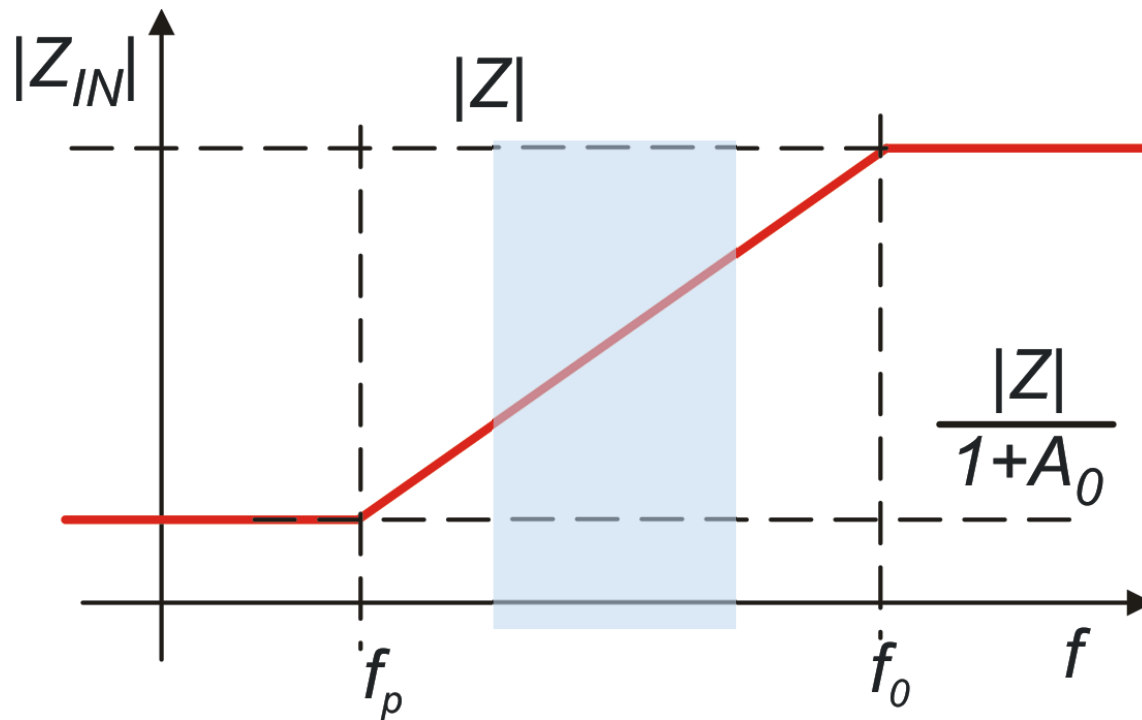
$$Z_{IN} = \frac{Z}{1 + A_0} \frac{1 + j \frac{f}{f_p}}{1 + j \frac{f}{f_0}}$$

$$f_0 \cong A_0 f_p \cong (1 + A_0) f_p$$

f_0 is defined as the frequency at which the amplifier gain magnitude is unity (0 dB)



TIA input impedance



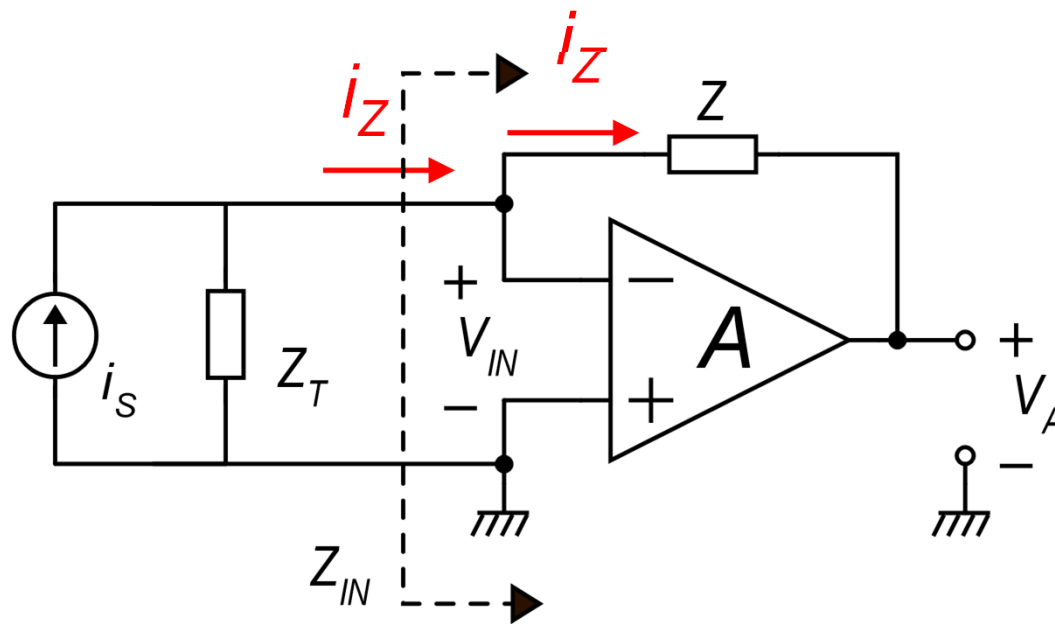
$$Z_{IN} = \frac{Z}{1+A_0} \frac{1+j\frac{f}{f_p}}{1+j\frac{f}{f_0}}$$

$$f_P \ll f \ll f_0$$

$$Z_{IN} = jZ \frac{f}{f_0}$$

Error due to the finite input impedance: (1) error on I_Z

Ideal case: $V_A = -Z \cdot I_S$



$$I_Z = I_S \frac{Z_T}{Z_{IN} + Z_T} = \frac{1}{1 + \frac{Z_{IN}}{Z_T}}$$

$$\text{if } |Z_{IN}| \ll |Z_T| \quad I_Z \cong I_S \left(1 - \frac{Z_{IN}}{Z_T} \right)$$

$$\epsilon_A \cong \left| \frac{Z_{IN}}{Z_T} \right| \quad \leftarrow \text{Error on current } I_Z$$

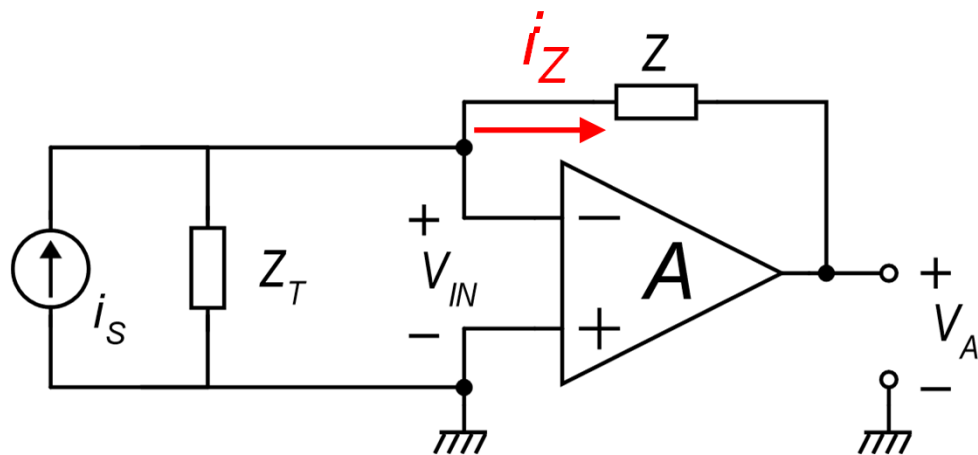
Error due to the finite input impedance: (2) error due to $V_{IN} \neq 0$

Ideal case: $V_A = -Z \cdot I_S$

$$V_A = v_{in} - I_Z Z \quad v_{in} = -\frac{V_A}{A}$$

$$V_A = \frac{-V_A}{A} - I_Z Z \Rightarrow V_A \left(1 + \frac{1}{A}\right) = -I_Z Z$$

$$V_A = -\frac{I_Z Z}{1 + \frac{1}{A}} \cong -I_Z Z \left(1 - \frac{1}{A}\right)$$



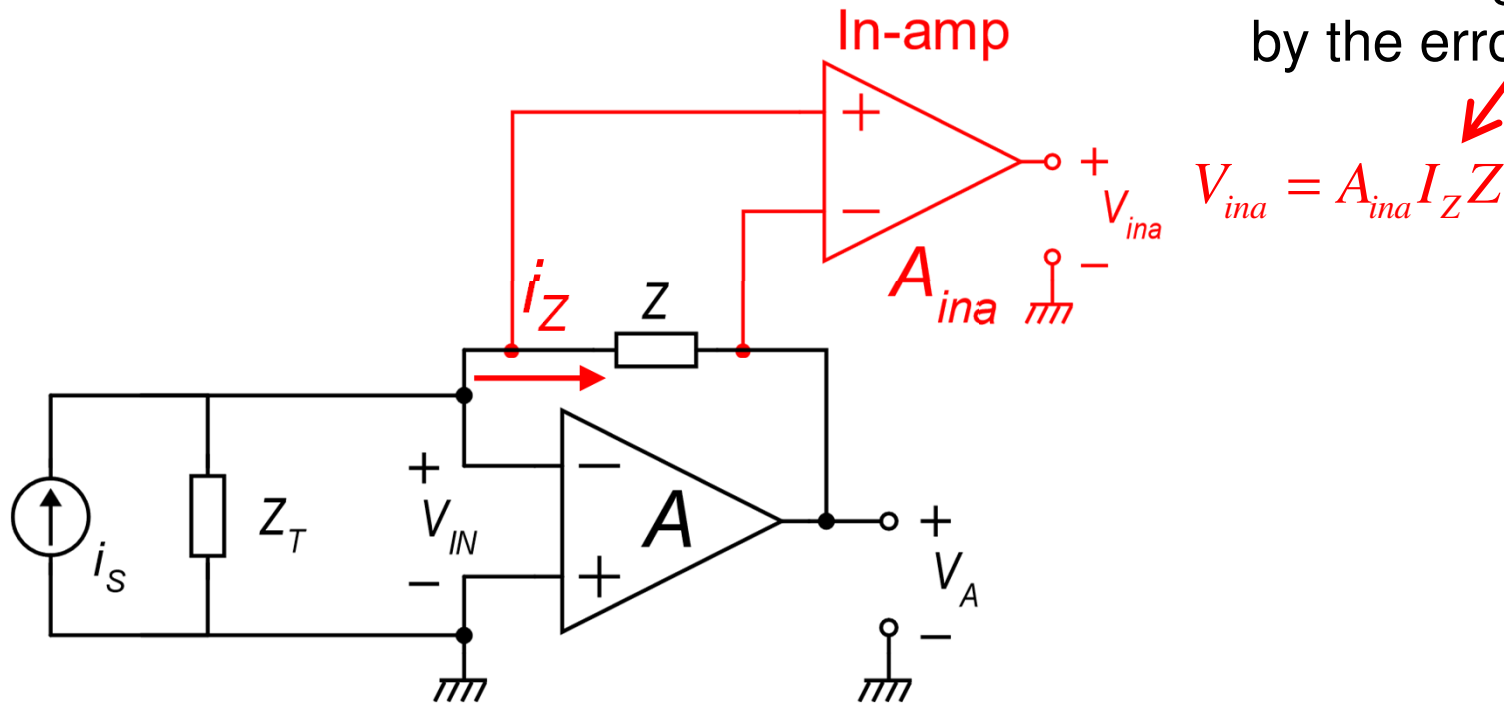
Relative
error contributions

$$\epsilon_A \cong \left| \frac{Z_{IN}}{Z_T} \right| \quad \frac{1}{|A(f)|}$$

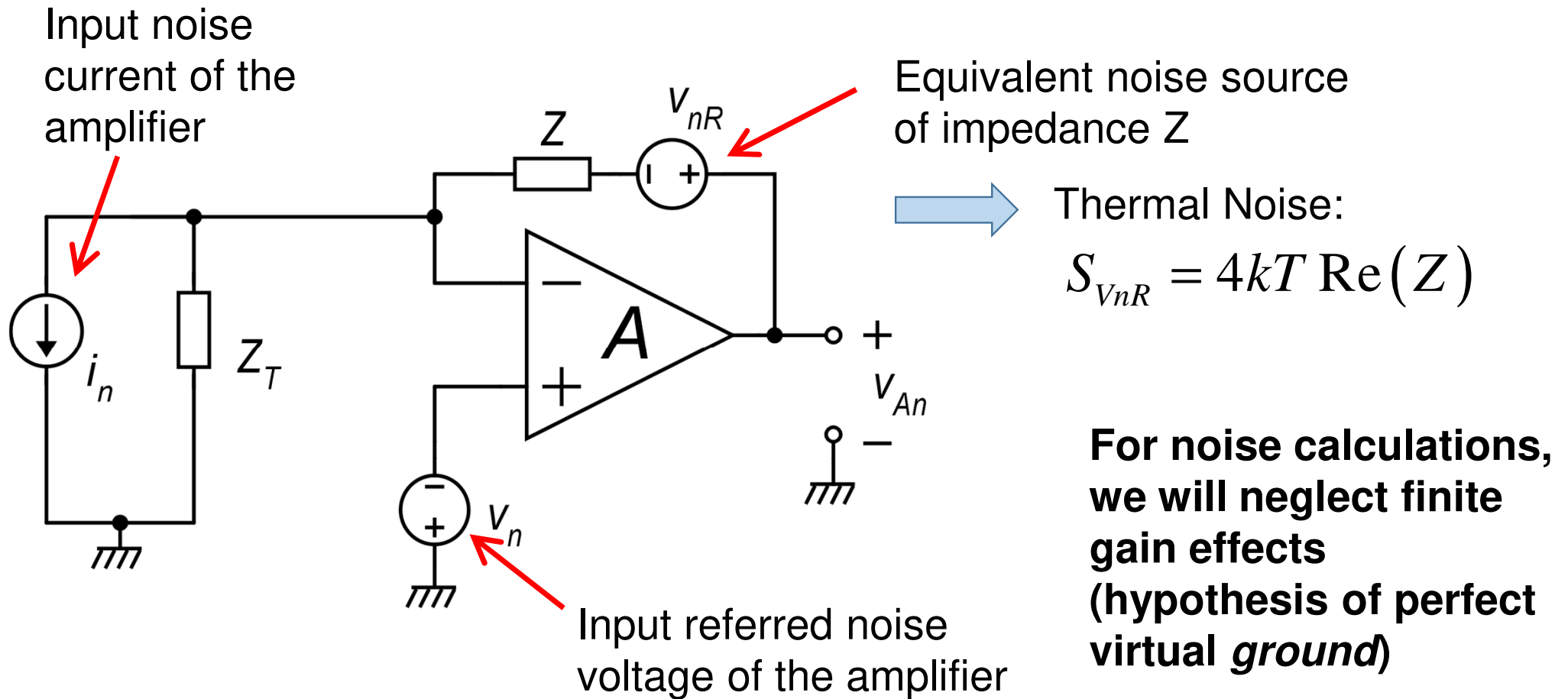
Reducing the $1/A$ error

Ideal case: $V_A = -Z \cdot I_S$

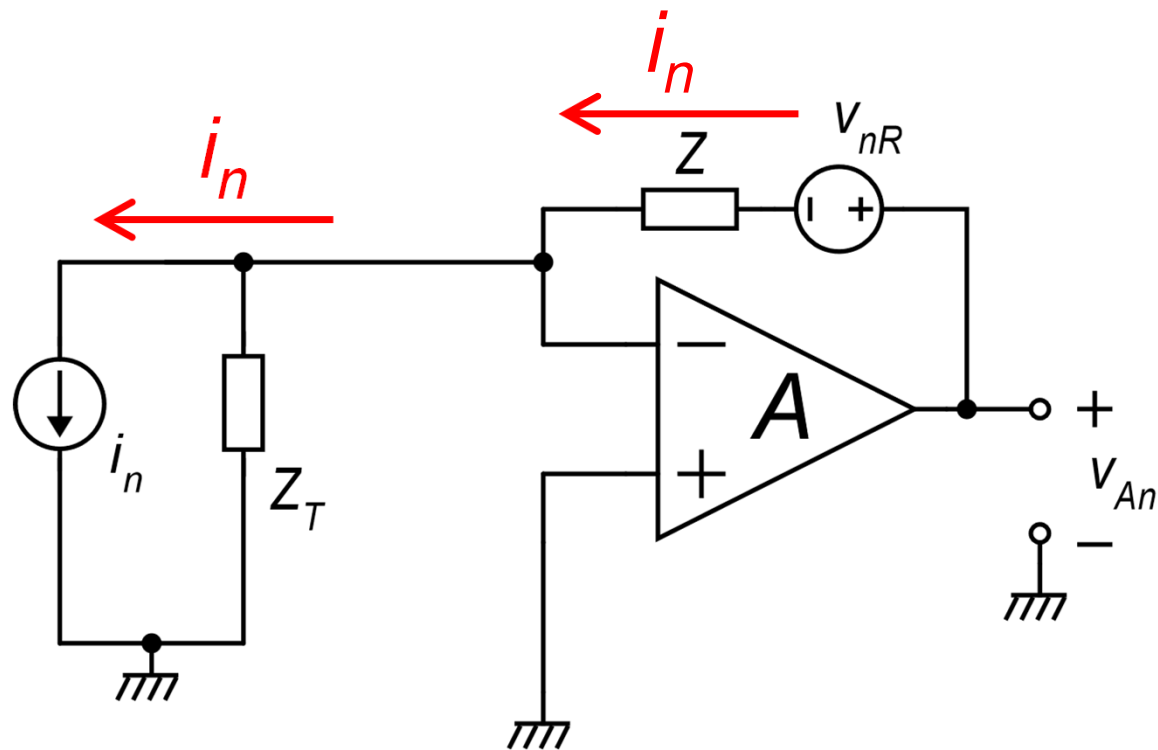
This voltage is affected only
by the error due to: $I_S \neq I_Z$



TIA non-ideality: Noise and offset

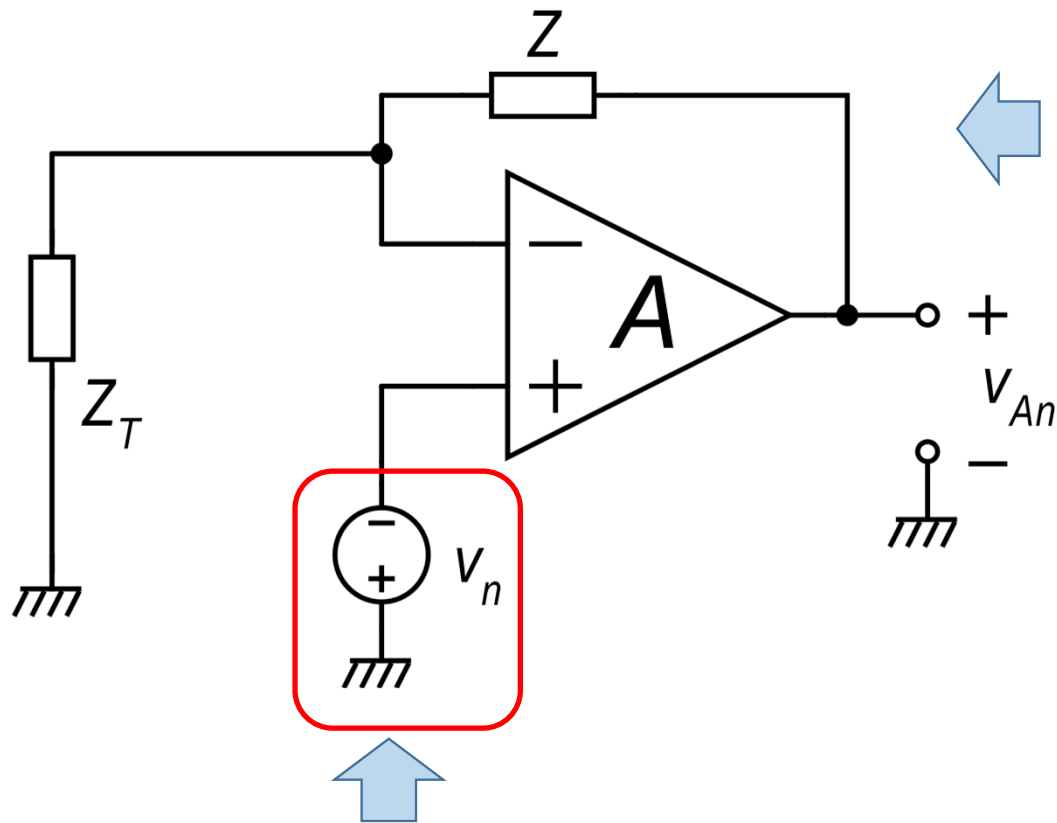


Effect of i_n and V_{nR}



$$v_{An} = i_n \cdot Z + v_{nR}$$

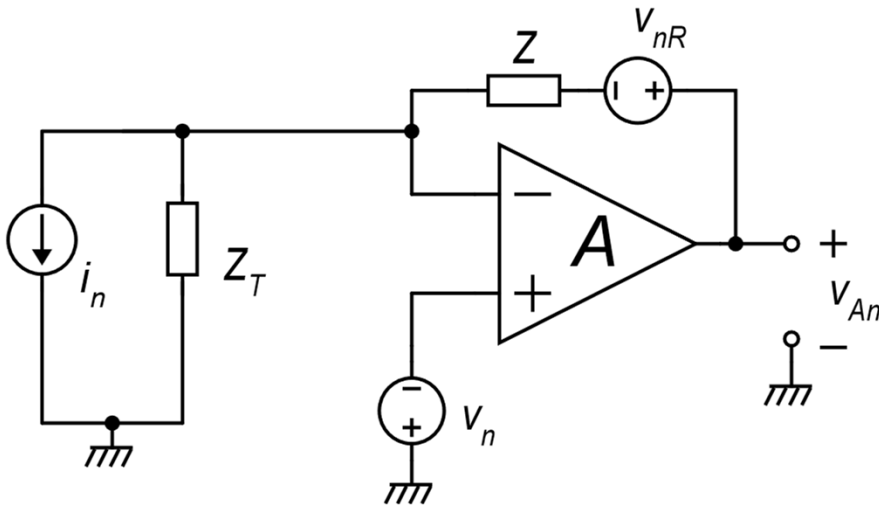
Effect of the voltage source



This is the classical non-inverting amplifier with $-v_n$ as input signal.

$$v_{An} = -v_n \left(1 + \frac{Z}{Z_T} \right)$$

Total output noise voltage and input referred noise current



$$v_{An} \cong Zi_n - v_n \left(1 + \frac{Z}{Z_T} \right) + v_{nR}$$

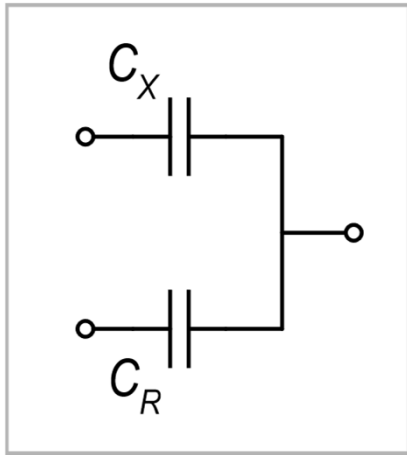
The quantity of interest is the total input-referred current noise: i_{n-RTI}

$$i_{n-RTI} = \frac{v_{An}}{k_{TIA}} \quad k_{TIA} = \frac{v_A}{i_s} = -Z$$

$$i_{n-RTI} \cong -i_n + v_n \left(\frac{1}{Z} + \frac{1}{Z_T} \right) - \frac{v_{nR}}{Z}$$

$$\text{for } Z \rightarrow \infty: i_{n-rti} = -i_n + \frac{v_n}{Z_T}$$

TIA used to read capacitive sensors



Differential capacitive sensor

X : physical quantity to be sensed

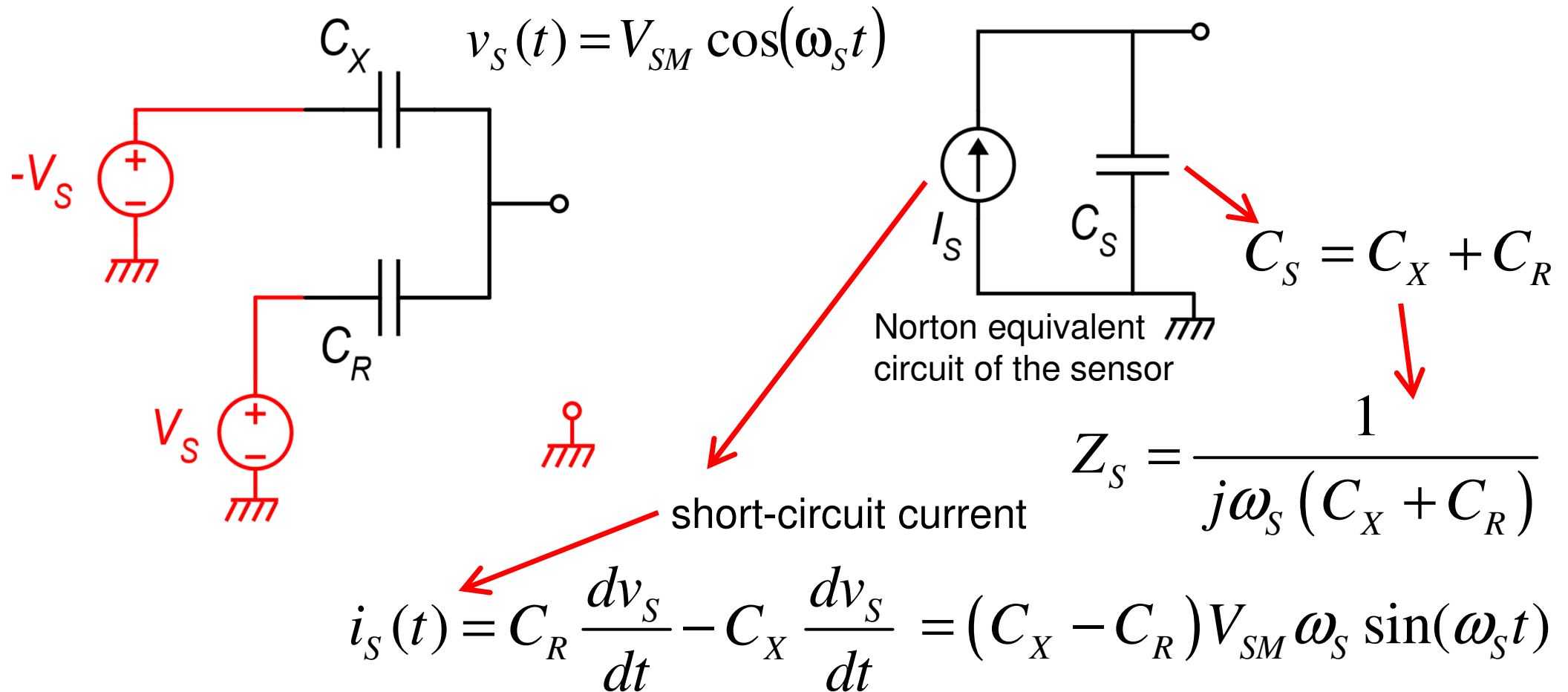
case 1 $\left\{ \begin{array}{l} C_X = C_0 + f(X) \\ C_R = C_0 - f(X) \end{array} \right.$ Balanced differential sensor (e.g. MEMS accelerometer)

case 2 $\left\{ \begin{array}{l} C_X = C_0 + f(X) \\ C_R = C_0 \end{array} \right.$ Pseudo differential sensor (e.g. pressure sensor)

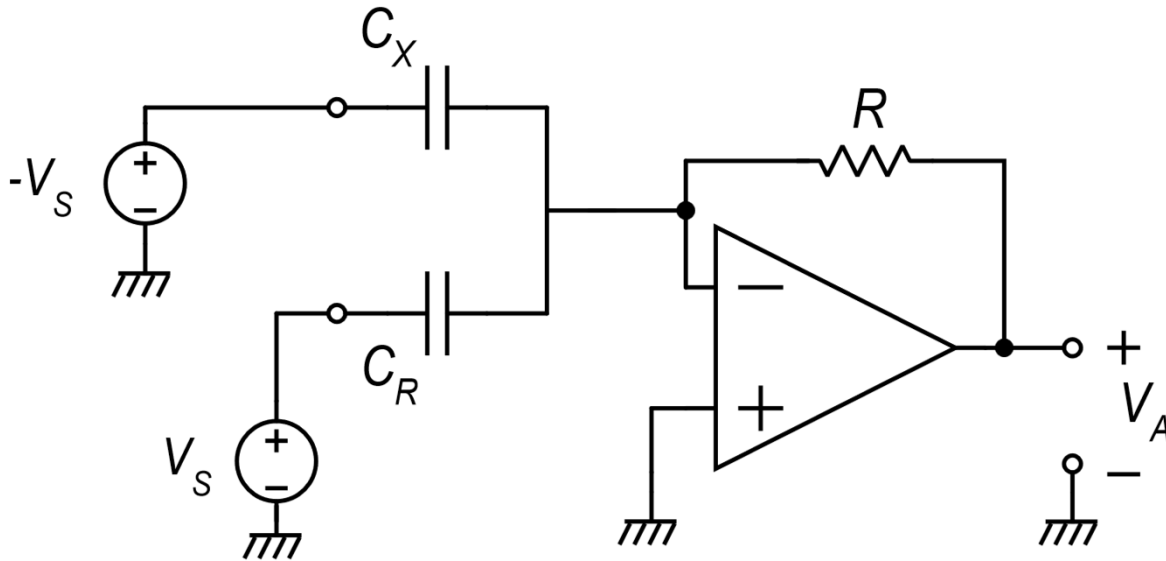
C_0 is typically a large capacitance which does not vary with X , but is widely affected by process spread and often depends on temperature

The interface must read: $\Delta C = C_X - C_R$

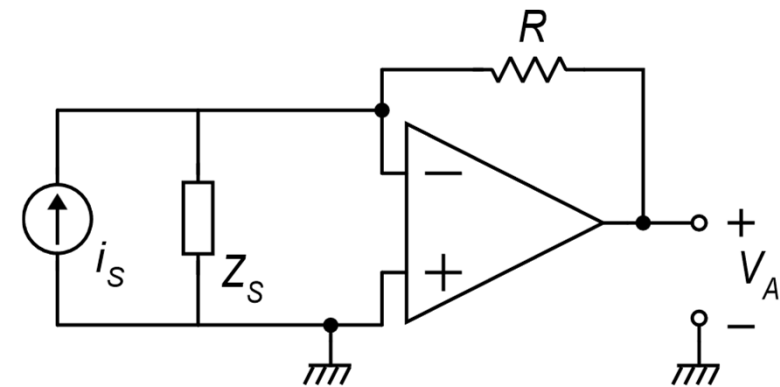
Transformation of ΔC into a current



Use of the TIA to read current I_S



Substituting the Norton equivalent circuit to the sensor, we have the usual TIA configuration, with $Z=R$



$$v_A(t) = -R \cdot i_S(t) = -\Delta C(t) \cdot R V_{SM} \omega_S \sin(\omega_S t)$$

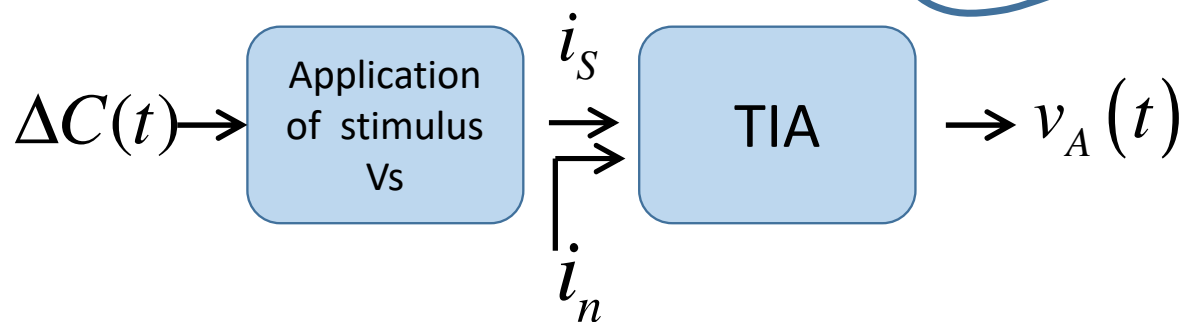
The useful signal $\Delta C(t)$ is modulated by $\sin(\omega_S t)$:

Demodulation is required to extract $\Delta C(t)$

Synchronous demodulation allows detecting also the sign of $\Delta C(t)$

A few general considerations

$$i_s(t) = \Delta C(t) \cdot V_{SM} \underbrace{\omega_s \sin(\omega_s t)}_{\text{It is desirable to increase this factor to have a larger signal-to-noise ratio}}$$



It is desirable to increase this factor to have a larger signal-to-noise ratio

$$\varepsilon_{tot} \cong \left| \frac{Z_{IN}}{Z_T} \right| + \frac{1}{|A(f)|}$$

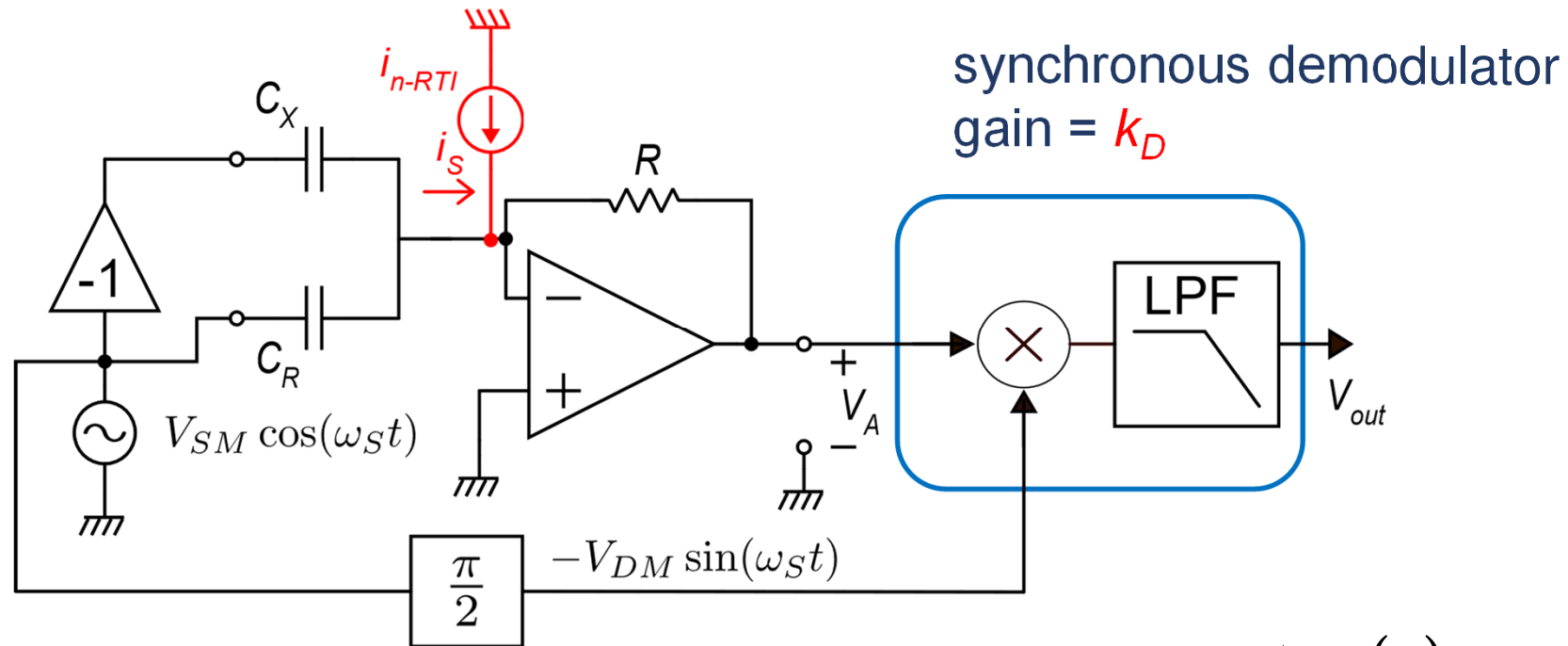
V_{SM} must be as large as possible (limited by V_{dd})

ω_s cannot be too large because the error due to the finite impedance becomes not acceptable.

if ω_s increases:

$$\left\{ \begin{array}{l} |A(f_s)| \text{ decreases} \\ |Z_{IN}| = R \frac{f_s}{f_0} \text{ increases} \\ |Z_T| = \frac{1}{\omega_s (C_s + C_A)} \text{ decreases} \end{array} \right.$$

Complete interface

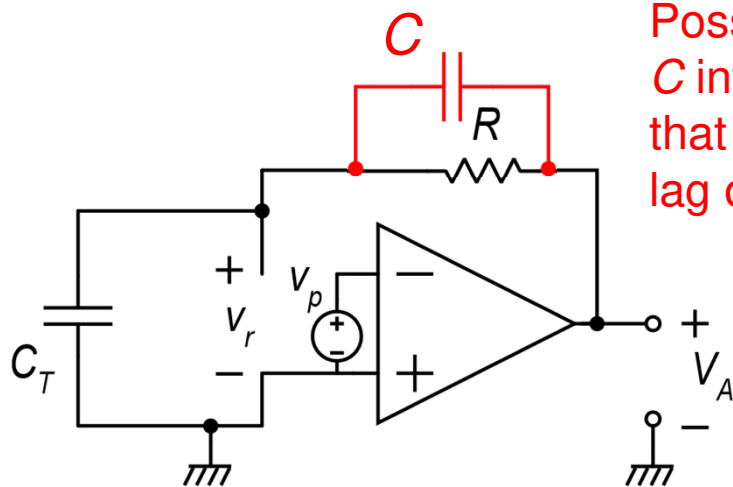
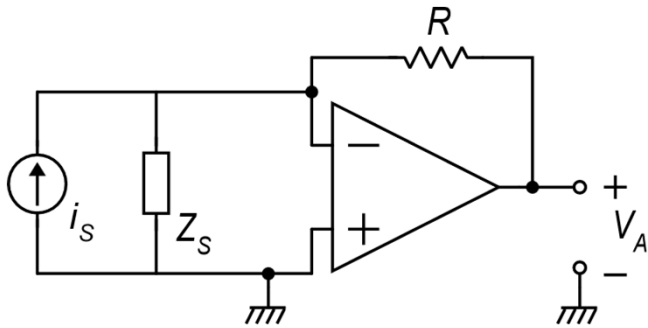


$$v_{out} = \Delta C(t) \cdot \mathbf{R} V_{SM} \omega_S \mathbf{k}_D$$

$$i_S = \Delta C(t) \cdot V_{SM} \omega_S \sin(\omega_S t)$$

$$v_A = -\Delta C(t) \cdot \mathbf{R} V_{SM} \omega_S \sin(\omega_S t) \quad (\text{ideal TIA})$$

Brief mention to TIA stability issues



Possible solution:
 C introduces a zero
 that reduces the phase
 lag due to f_β

